# **Single D Flip Flop**

The NL17SZ74 is a high performance, full function Edge triggered D Flip Flop, with all the features of a standard logic device such as the 74LCX74.

#### **Features**

- Extremely High Speed:  $t_{PD}$  2.6 ns (typical) at  $V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- 5.0 V Tolerant Inputs Interface Capability with 5.0 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10 μA) Substantially Reduces System Power Requirements
- Replacement for NC7SZ74
- Tiny Ultra Small Package Only 2.1 X 3.0 mm
- High ESD Ratings: 4000 V Human Body Model 200 V Machine Model
- Chip Complexity: FET = 64
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

## **TRUTH TABLE**

|             | Inputs      |             |             | Out         | outs        |  |  |  |
|-------------|-------------|-------------|-------------|-------------|-------------|--|--|--|
| PR          | CLR         | СР          | D           | Q           | Q           | Operating Mode   |  |  |
| L<br>H<br>L | H<br>L<br>L | X<br>X<br>X | X<br>X<br>X | H<br>L<br>H | L<br>H<br>H | Asynchronous Set<br>Asynchronous Clear<br>Undetermined |  |  |
| H           | H<br>H      | <b>↑</b>    | h<br>I      | H<br>L      | L<br>H      | Load and Read Register                                 |  |  |
| Н           | Н           | 1           | Х           | NC          | NC          | Hold   |  |  |

H = High Voltage Level

 = High Voltage Level One Setup Time Prior to the Low-to-High Clock Transition

L = Low Voltage Level

 Low Voltage Level One Setup Time Prior to the Low-to-High Clock Transition

1

NC = No Change

X = High or Low Voltage Level and Transitions are Acceptable

↑ = Low-to-High Transition

For  $I_{CC}$  reasons, DO NOT FLOAT Inputs



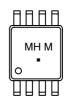
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http://onsemi.com



US8 US SUFFIX CASE 493

#### **MARKING DIAGRAM**



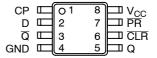
MH = Specific Device Code

M = Date Code

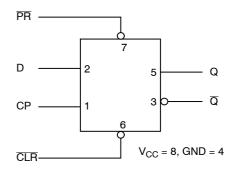
■ = Pb-Free Package

(Note: Microdot may be in either location)

#### **PINOUT DIAGRAM**



## LOGIC DIAGRAM



## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

#### **MAXIMUM RATINGS**

| Symbol               | Parameter  | Value                        | Units |
|----------------------|--|------------------------------|-------|
| V <sub>CC</sub>      | DC Supply Voltage  | -0.5 to +7.0                 | V     |
| VI                   | DC Input Voltage   | -0.5 to +7.0                 | V     |
| Vo                   | DC Output Voltage – Output in High or Low State (Note 1)   | -0.5 to V <sub>CC</sub> +0.5 | V     |
| I <sub>IK</sub>      | DC Input Diode Current V <sub>I</sub> < GND  | -50                          | mA    |
| lok                  | DC Output Diode Current V <sub>O</sub> < GND   | -50                          | mA    |
| Ιο                   | DC Output Sink Current   | ±50                          | mA    |
| I <sub>CC</sub>      | DC Supply Current Per Supply Pin   | ±100                         | mA    |
| I <sub>GND</sub>     | DC Ground Current Per Ground Pin   | ±100                         | mA    |
| T <sub>STG</sub>     | Storage Temperature Range  | -65 to +150                  | °C    |
| TL                   | Lead Temperature, 1 mm from Case for 10 Seconds  | 260                          | °C    |
| T <sub>J</sub>       | Junction Temperature Under Bias  | +150                         | °C    |
| $\theta_{\sf JA}$    | Thermal Resistance (Note 2)  | 250                          | °C/W  |
| P <sub>D</sub>       | Power Dissipation in Still Air at 85°C   | 250                          | mW    |
| MSL                  | Moisture Sensitivity   | Level 1                      |       |
| F <sub>R</sub>       | Flammability Rating, Oxygen Index: 28 to 34  | UL 94 V-0 @ 0.125 in         |       |
| V <sub>ESD</sub>     | ESD Withstand Voltage Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5) | >4000<br>>200<br>N/A         | V     |
| I <sub>LATCHUP</sub> | Latchup Performance Above V <sub>CC</sub> and Below GND at 125°C (Note 6)                            | ±100                         | mA    |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. I<sub>O</sub> absolute maximum rating must be observed.
- 2. Measured with minimum pad spacing on an FR4 board, using 10 mm X 1 inch, 2 ounce copper trace with no air flow.
- 3. Tested to EIA/JESD22-A114-A.
- 4. Tested to EIA/JESD22-A115-A.
- 5. Tested to JESD22-C101-A.
- 6. Tested to EIA/JESD78.

## **RECOMMENDED OPERATING CONDITIONS**

| Symbol          | Parameter                                   | Min  | Max  | Units |
|-----------------|---|------|------|-------|
| V <sub>CC</sub> | Supply Voltage                              |      |      | V     |
|                 | Operating                                   | 1.65 | 5.5  |       |
|                 | Data Retention Only                         | 1.5  | 5.5  |       |
| V <sub>I</sub>  | Input Voltage (Note 7)                      | 0    | 5.5  | V     |
| Vo              | Output Voltage (HIGH or LOW State)          | 0    | 5.5  | V     |
| T <sub>A</sub>  | Operating Free-Air Temperature              | -55  | +125 | °C    |
| Δt/ΔV           | Input Transition Rise or Fall Rate          |      |      | ns/V  |
|                 | $V_{CC} = 2.5 \text{ V } \pm 0.2 \text{ V}$ | 0    | 20   |       |
|                 | $V_{CC} = 3.0 \text{ V } \pm 0.3 \text{ V}$ | 0    | 10   |       |
|                 | $V_{CC} = 5.0 \text{ V } \pm 0.5 \text{ V}$ | 0    | 5.0  |       |

<sup>7.</sup> Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

## **ORDERING INFORMATION**

| Device        | Package          | Shipping <sup>†</sup> |
|---------------|------------------|-----------------------|
| NL17SZ74USG   | US8<br>(Pb-Free) | 3000 / Tape & Reel    |
| NLV17SZ74USG* | US8<br>(Pb-Free) | 3000 / Tape & Reel    |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

## DC ELECTRICAL CHARACTERISTICS

|                  |                                      |  | V <sub>CC</sub> | Т                     | A = 25°C |                      | -55°C ≤ T <sub>A</sub> ≤ 125°C |                      |       |
|------------------|--------------------------------------|--|-----------------|-----------------------|----------|----------------------|--------------------------------|----------------------|-------|
| Symbol           | Parameter                            | Condition  | (V)             | Min                   | Тур      | Max                  | Min                            | Max                  | Units |
| V <sub>IH</sub>  | High-Level Input Voltage             |  | 1.65            | 0.75 V <sub>CC</sub>  |          |                      | 0.75 V <sub>CC</sub>           |                      | V     |
|                  |                                      |  | 2.3 to 5.5      | 0.7 V <sub>CC</sub>   |          |                      | 0.7 V <sub>CC</sub>            |                      |       |
| V <sub>IL</sub>  | Low-Level Input Voltage              |  | 1.65            |                       |          | 0.25 V <sub>CC</sub> |                                | 0.25 V <sub>CC</sub> | ٧     |
|                  |                                      |  | 2.3 to 5.5      |                       |          | 0.3 V <sub>CC</sub>  |                                | 0.3 V <sub>CC</sub>  |       |
| V <sub>OH</sub>  | High-Level Output Voltage            | I <sub>OH</sub> = 100 μA                               | 1.65 to 5.5     | V <sub>CC</sub> - 0.1 | $V_{CC}$ |                      | V <sub>CC</sub> - 0.1          |                      | ٧     |
|                  | $V_{IN} = V_{IL} \text{ or } V_{IL}$ | $I_{OH} = -3 \text{ mA}$                               | 1.65            | 1.29                  | 1.52     |                      | 1.29                           |                      |       |
|                  |                                      | $I_{OH} = -8 \text{ mA}$                               | 2.3             | 1.9                   | 2.1      |                      | 1.9                            |                      |       |
|                  |                                      | $I_{OH} = -12 \text{ mA}$                              | 2.7             | 2.2                   | 2.4      |                      | 2.2                            |                      |       |
|                  |                                      | $I_{OH} = -16 \text{ mA}$                              | 3.0             | 2.4                   | 2.7      |                      | 2.4                            |                      |       |
|                  |                                      | $I_{OH} = -24 \text{ mA}$                              | 3.0             | 2.3                   | 2.5      |                      | 2.3                            |                      |       |
|                  |                                      | $I_{OH} = -32 \text{ mA}$                              | 4.5             | 3.8                   | 4.0      |                      | 3.8                            |                      |       |
| V <sub>OL</sub>  | Low-Level Output Voltage             | I <sub>OL</sub> = 100 μA                               | 1.65 to 5.5     |                       | 0.008    | 0.1                  |                                | 0.1                  | V     |
|                  | $V_{IN} = V_{IH}$                    | $I_{OL} = 3 \text{ mA}$                                | 1.65            |                       | 0.10     | 0.24                 |                                | 0.24                 |       |
|                  |                                      | $I_{OL} = 8 \text{ mA}$                                | 2.3             |                       | 0.12     | 0.3                  |                                | 0.3                  |       |
|                  |                                      | I <sub>OL</sub> = 12 mA                                | 2.7             |                       | 0.15     | 0.4                  |                                | 0.4                  |       |
|                  |                                      | I <sub>OL</sub> = 16 mA                                | 3.0             |                       | 0.19     | 0.4                  |                                | 0.4                  |       |
|                  |                                      | I <sub>OL</sub> = 24 mA                                | 3.0             |                       | 0.30     | 0.55                 |                                | 0.55                 |       |
|                  |                                      | I <sub>OL</sub> = 32 mA                                | 4.5             |                       | 0.30     | 0.55                 |                                | 0.55                 |       |
| I <sub>IN</sub>  | Input Leakage Current                | V <sub>IN</sub> = 5.5 V or<br>GND                      | 0 to 5.5        |                       |          | ±0.1                 |                                | ±1.0                 | μΑ    |
| I <sub>OFF</sub> | Power Off<br>Leakage Current         | V <sub>IN</sub> = 5.5 V or<br>V <sub>OUT</sub> = 5.5 V | 0               |                       |          | 1.0                  |                                | 10                   | μΑ    |
| I <sub>CC</sub>  | Quiescent Supply Current             | V <sub>IN</sub> = 5.5 V or<br>GND                      | 5.5             |                       |          | 1.0                  |                                | 10                   | μΑ    |

Capable.

#### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

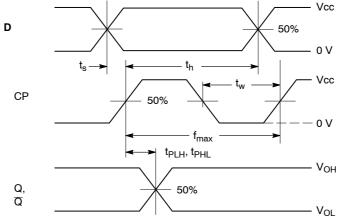
|                    |                                    |                     |                                       | •   | Γ <sub>A</sub> = 25°( | С    | T <sub>A</sub> = -55 to 125°C |      |       |
|--------------------|------------------------------------|---------------------|---------------------------------------|-----|-----------------------|------|-------------------------------|------|-------|
| Symbol             | Parameter                          | V <sub>CC</sub> (V) | Test Conditions                       | Min | Тур                   | Max  | Min                           | Max  | Units |
| f <sub>MAX</sub>   | Maximum Clock                      | 1.8 ± 0.15          | C <sub>L</sub> = 15 pF                | 75  |                       |      | 75                            |      | MHz   |
|                    | Frequency                          | 2.5 ± 0.2           | $R_D = 1 M\Omega$                     | 150 |                       |      | 150                           |      |       |
|                    | (50% Duty Cycle)                   | 3.3 ± 0.3           | S <sub>1</sub> = Open                 | 200 |                       |      | 200                           |      |       |
|                    | (Waveform 1)                       | 5.0 ± 0.5           | -                                     | 250 |                       |      | 250                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 175 |                       |      | 175                           |      |       |
|                    |                                    | 5.0 ± 0.5           | $R_D = 500 \Omega$ , $S_1 = Open$     | 200 |                       |      | 200                           |      |       |
| t <sub>PLH</sub> , | Propagation Delay,                 | 1.8 ± 0.15          | C <sub>L</sub> = 15 pF                | 2.5 | 6.5                   | 12.5 | 2.5                           | 13   | ns    |
| $t_{PHL}$          | CP to Q or $\overline{\mathbb{Q}}$ | $2.5 \pm 0.2$       | $R_D = 1 M\Omega$                     | 1.5 | 3.8                   | 7.5  | 1.5                           | 8.0  |       |
|                    | (Waveform 1)                       | $3.3 \pm 0.3$       | S <sub>1</sub> = Open                 | 1.0 | 2.8                   | 6.5  | 1.0                           | 7.0  |       |
|                    |                                    | 5.0 ± 0.5           | -                                     | 0.8 | 2.2                   | 4.5  | 0.8                           | 5.0  |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 1.0 | 3.4                   | 7.0  | 1.0                           | 7.5  |       |
|                    |                                    | 5.0 ± 0.5           | $R_D = 500 \Omega$ , $S_1 = Open$     | 1.0 | 2.6                   | 5.0  | 1.0                           | 5.5  |       |
| t <sub>PLH</sub> , | Propagation Delay,                 | 1.8 ± 0.15          | C <sub>L</sub> = 15 pF                | 2.5 | 6.5                   | 14   | 2.5                           | 14.5 | ns    |
| t <sub>PHL</sub>   | PR or CLR to Q or Q                | 2.5 ± 0.2           | $R_D = 1 M\Omega$                     | 1.5 | 3.8                   | 9.0  | 1.5                           | 9.5  |       |
|                    | (Waveform 2)                       | $3.3 \pm 0.3$       | S <sub>1</sub> = Open                 | 1.0 | 2.8                   | 6.5  | 1.0                           | 7.0  | 1     |
|                    |                                    | 5.0 ± 0.5           | -                                     | 0.8 | 2.2                   | 5.0  | 0.8                           | 5.5  |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 1.0 | 3.4                   | 7.0  | 1.0                           | 7.5  |       |
|                    |                                    | 5.0 ± 0.5           | $R_D = 500 \Omega$ , $S_1 = Open$     | 1.0 | 2.6                   | 5.0  | 1.0                           | 5.5  |       |
| t <sub>S</sub>     | Setup Time, D to CP                | 1.8 ± 0.15          | $C_L$ = 15 pF<br>$R_D$ = 1 M $\Omega$ | 6.5 |                       |      | 6.5                           |      | ns    |
|                    | (Waveform 1)                       | $2.5 \pm 0.2$       |                                       | 3.5 |                       |      | 3.5                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | S <sub>1</sub> = Open                 | 2.0 |                       |      | 2.0                           |      |       |
|                    |                                    | 5.0 ± 0.5           |                                       | 1.5 |                       |      | 1.5                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 2.0 |                       |      | 2.0                           |      |       |
|                    |                                    | $5.0 \pm 0.5$       | $R_D = 500 \Omega$ , $S_1 = Open$     | 1.5 |                       |      | 1.5                           |      |       |
| t <sub>H</sub>     | Hold Time, D to CP                 | 1.8 ± 0.15          | C <sub>L</sub> = 15 pF                | 0.5 |                       |      | 0.5                           |      | ns    |
|                    | (Waveform 1)                       | $2.5 \pm 0.2$       | $R_D = 1 M\Omega$                     | 0.5 |                       |      | 0.5                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | S <sub>1</sub> = Open                 | 0.5 |                       |      | 0.5                           |      |       |
|                    |                                    | 5.0 ± 0.5           | -                                     | 0.5 |                       |      | 0.5                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 0.5 |                       |      | 0.5                           |      |       |
|                    |                                    | 5.0 ± 0.5           | $R_D = 500 \Omega$ , $S_1 = Open$     | 0.5 |                       |      | 0.5                           |      |       |
| t <sub>W</sub>     | Pulse Width,                       | 1.8 ± 0.15          | C <sub>L</sub> = 15 pF                | 6.0 |                       |      | 6.0                           |      | ns    |
|                    | CP, CLR, PR                        | $2.5 \pm 0.2$       | $R_D = 1 M\Omega$                     | 4.0 |                       |      | 4.0                           |      | 1     |
|                    | (Waveform 3)                       | $3.3 \pm 0.3$       | S <sub>1</sub> = Open                 | 3.0 |                       |      | 3.0                           |      |       |
|                    |                                    | $5.0 \pm 0.5$       |                                       | 2.0 |                       |      | 2.0                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 3.0 |                       |      | 3.0                           |      |       |
|                    |                                    | $5.0 \pm 0.5$       | $R_D = 500 \Omega$ , $S_1 = Open$     | 2.0 |                       |      | 2.0                           |      |       |
| t <sub>REC</sub>   | Recover Time                       | 1.8 ± 0.15          | C <sub>L</sub> = 15 pF                | 8.0 |                       |      | 8.0                           |      | MHz   |
|                    | PR; CLR to CP                      | $2.5 \pm 0.2$       | $R_D = 1 M\Omega$                     | 4.5 |                       |      | 4.5                           |      |       |
|                    | (Waveform 3)                       | $3.3 \pm 0.3$       | S <sub>1</sub> = Open                 | 3.0 |                       |      | 3.0                           |      |       |
|                    |                                    | 5.0 ± 0.5           | 1                                     | 3.0 |                       |      | 3.0                           |      |       |
|                    |                                    | $3.3 \pm 0.3$       | C <sub>L</sub> = 50 pF,               | 3.0 |                       |      | 3.0                           |      |       |
|                    |                                    | 5.0 ± 0.5           | $R_D$ = 500 Ω, $S_1$ = Open           | 3.0 |                       |      | 3.0                           |      |       |

<sup>8.</sup> CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}/2$  (per flip-flop).  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

#### **CAPACITANCE** (Note 9)

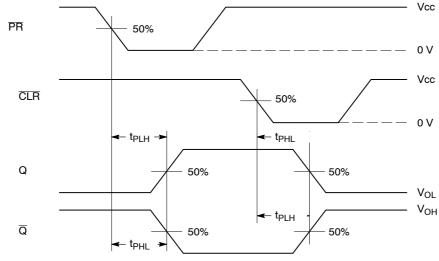
| Symbol           | Parameter  | Condition  | Typical  | Unit |
|------------------|--|--|----------|------|
| C <sub>IN</sub>  | Input Capacitance  | V <sub>CC</sub> = 5.5 V                            | 7.0      | pF   |
| C <sub>OUT</sub> | Output Capacitance   | V <sub>CC</sub> = 5.5 V                            | 7.0      | pF   |
| C <sub>PD</sub>  | Power Dissipation Capacitance (Note 10) Frequency = 10 MHz | V <sub>CC</sub> = 3.3 V<br>V <sub>CC</sub> = 5.0 V | 16<br>21 | pF   |

<sup>9.</sup> T<sub>A</sub> = +25°C, f = 1 MHz
10. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. (See Figure 1) C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression:  $I_{CCD} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC(static)}$ .



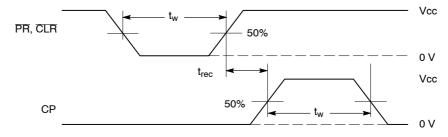
## WAVEFORM 1 - PROPAGATION DELAYS, SETUP AND HOLD TIMES

 $t_{R}$  =  $t_{F}$  = 3.0 ns, 10% to 90%; f = 1 MHz;  $t_{W}$  = 500 ns



## WAVEFORM 2 - PROPAGATION DELAYS

 $t_R = t_F = 3.0 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$ 



## **WAVEFORM 3 – RECOVERY TIME**

 $t_R$  =  $t_F$  = 3.0 ns from 10% to 90%; f = 1 MHz;  $t_w$  = 500 ns Output Reg:  $V_{OL} \le$  0.8 V,  $V_{OH} \ge$  2.0 V

Figure 1. AC Waveforms

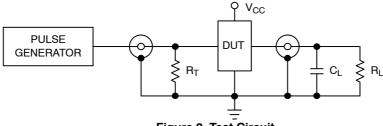
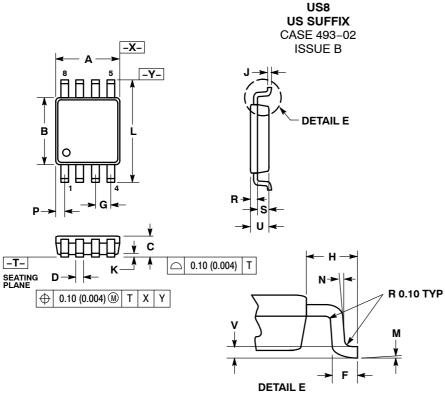


Figure 2. Test Circuit

#### PACKAGE DIMENSIONS



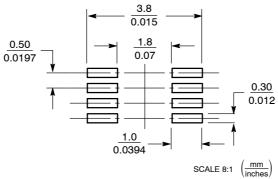
#### NOTES:

- DIMENSIONING AND TOLERANCING PER
  ANSI V14 5M 1982
- ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.140 MM (0.0055") PER SIDE.
- 4. DIMENSION "B" DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSION. INTER-LEAD FLASH AND PROTRUSION SHALL NOT E3XCEED 0.140 (0.0055") PER SIDE.
- 5. LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM. (300-800 °).
- (300–800 °).

  6. ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 (0.0002 °).

|     | MILLIN | IETERS | INC       | HES   |  |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN    | MAX    | MIN       | MAX   |  |
| Α   | 1.90   | 2.10   | 0.075     | 0.083 |  |
| В   | 2.20   | 2.40   | 0.087     | 0.094 |  |
| С   | 0.60   | 0.90   | 0.024     | 0.035 |  |
| D   | 0.17   | 0.25   | 0.007     | 0.010 |  |
| F   | 0.20   | 0.35   | 0.008     | 0.014 |  |
| G   | 0.50   | BSC    | 0.020     | BSC   |  |
| н   | 0.40   | REF    | 0.016 REF |       |  |
| J   | 0.10   | 0.18   | 0.004     | 0.007 |  |
| K   | 0.00   | 0.10   | 0.000     | 0.004 |  |
| L   | 3.00   | 3.20   | 0.118     | 0.126 |  |
| М   | 0 °    | 6 °    | 0 °       | 6 °   |  |
| N   | 5 °    | 10 °   | 5 °       | 10 °  |  |
| Р   | 0.23   | 0.34   | 0.010     | 0.013 |  |
| R   | 0.23   | 0.33   | 0.009     | 0.013 |  |
| S   | 0.37   | 0.47   | 0.015     | 0.019 |  |
| U   | 0.60   | 0.80   | 0.024     | 0.031 |  |
| ٧   | 0.12   | BSC    | 0.005     | BSC   |  |

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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